Complementary Silicon Power Transistors

These complementary silicon power transistors are designed for high-speed switching applications, such as switching regulators and high frequency inverters. The devices are also well-suited for drivers for high power switching circuits.

Features

- Fast Switching
- Key Parameters Specified @ 100°C
- Low Collector-Emitter Saturation Voltage
- Complementary Pairs Simplify Circuit Designs
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	80	Vdc
Collector–Emitter Voltage	V _{CEV}	100	Vdc
Emitter Base Voltage	V _{EB}	7.0	Vdc
Collector Current – Continuous	Ic	15	Adc
Collector Current – Peak (Note 1)	I _{CM}	20	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	83 0.67	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Width \leq 6.0 ms, Duty Cycle \leq 50%.

THERMAL CHARACTERISTICS

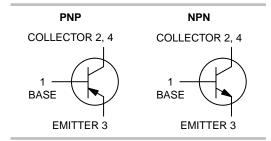
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.5	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	TL	275	°C

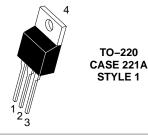


ON Semiconductor®

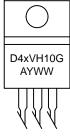
www.onsemi.com

15 A COMPLEMENTARY SILICON POWER TRANSISTORS 80 V, 83 W





MARKING DIAGRAM



x = 4 or 5

A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
D44VH10G	TO-220 (Pb-Free)	50 Units/Rail
D45VH10G	TO-220 (Pb-Free)	50 Units/Rail

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 25 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	80	-	-	Vdc
Collector–Emitter Cutoff Current (V_{CE} = Rated V_{CEV} , $V_{BE(off)}$ = 4.0 Vdc) (V_{CE} = Rated V_{CEV} , $V_{BE(off)}$ = 4.0 Vdc, T_{C} = 100°C)	I _{CEV}	- -	- -	10 100	μAdc
Emitter Base Cutoff Current (V _{EB} = 7.0 Vdc, I _C = 0)	I _{EBO}	-	_	10	μAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain ($I_C = 2.0$ Adc, $V_{CE} = 1.0$ Vdc) ($I_C = 4.0$ Adc, $V_{CE} = 1.0$ Vdc)	h _{FE}	35 20	_ _	_ _	-
Collector–Emitter Saturation Voltage (I _C = 8.0 Adc, I _B = 0.4 Adc) D44VH10	V _{CE(sat)}	_	_	0.4	Vdc
$(I_C = 8.0 \text{ Adc}, I_B = 0.8 \text{ Adc})$ D45VH10 $(I_C = 15 \text{ Adc}, I_B = 3.0 \text{ Adc}, T_C = 100^{\circ}\text{C})$		-	_	1.0	
D44VH10 D45VH10		- -	_ _	0.8 1.5	
Base–Emitter Saturation Voltage (I _C = 8.0 Adc, I _B = 0.4 Adc)	V _{BE(sat)}			4.0	Vdc
D44VH10 ($I_C = 8.0 \text{ Adc}, I_B = 0.8 \text{ Adc}$) D45VH10		_	_	1.2	
(I _C = 8.0 Adc, I _B = 0.4 Adc, T _C = 100°C) D44VH10 (I _C = 8.0 Adc, I _B = 0.8 Adc, T _C = 100°C)		-	-	1.1	
D45VH10		-	_	1.5	
DYNAMIC CHARACTERISTICS					
Current Gain Bandwidth Product $(I_C = 0.1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 20 \text{ MHz})$	f _T	_	50	-	MHz
Output Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_{C} = 0$, $f_{test} = 1.0 \text{ MHz}$)	C _{ob}				pF
D44VH10 D45VH10		- -	120 275	-	
SWITCHING CHARACTERISTICS					
Delay Time	t _d	-		50	ns
Rise Time	t _r	_	_	250	
Storage Time $(V_{CC} = 20 \text{ Vdc}, I_C = 8.0 \text{ Adc}, I_{B1} = I_{B2} = 0.8 \text{ Adc})$	t _s	-	_	700	
Fall Time	t _f	-	-	90	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

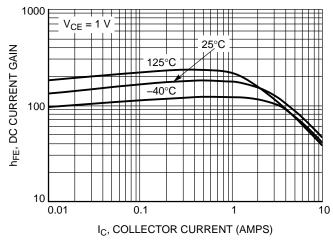


Figure 1. D44VH10 DC Current Gain

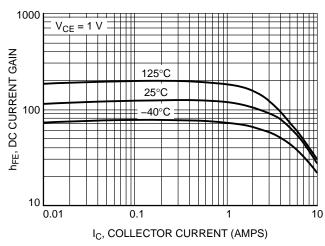


Figure 2. D45VH10 DC Current Gain

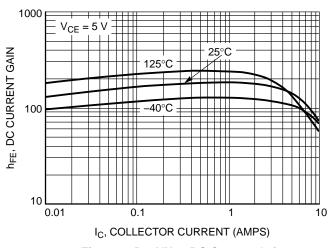


Figure 3. D44VH10 DC Current Gain

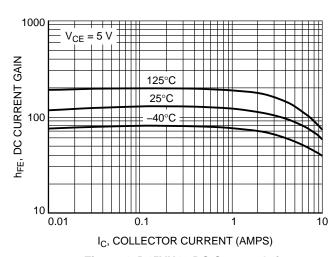


Figure 4. D45VH10 DC Current Gain

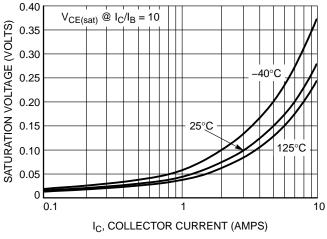


Figure 5. D44VH10 ON-Voltage

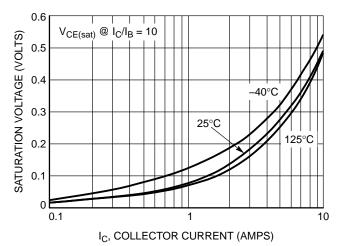


Figure 6. D45VH10 ON-Voltage

1.4

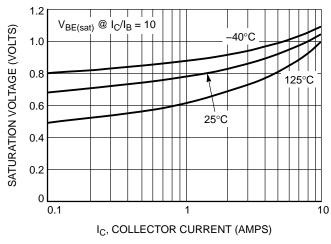
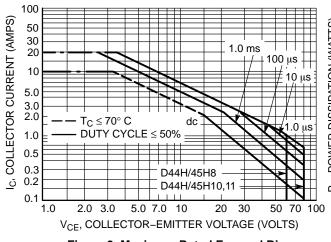


Figure 7. D44VH10 ON-Voltage

Figure 8. D45VH10 ON-Voltage



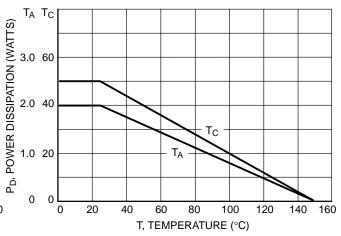


Figure 9. Maximum Rated Forward Bias Safe Operating Area

Figure 10. Power Derating

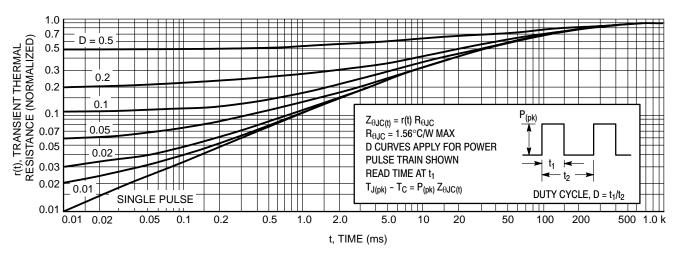
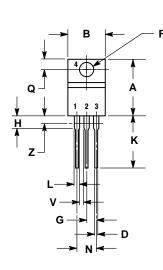
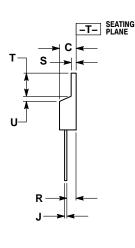


Figure 11. Thermal Response

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
J	0.014	0.024	0.36	0.61	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 1:

BASE PIN 1.

- COLLECTOR
- **EMITTER** 3
- COLLECTOR

ON Semiconductor and the 👊 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any licensee under its patent rights of others. SCILLC products are not designed, intended, or other applications in systems in systems intended for surprised for use as components in systems insystems in systems in systems intended for parameters in systems in systems. or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

D44VH10G D45VH10G